

Automotive Dual P-Channel 30 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY	
V _{DS} (V)	- 30
$R_{DS(on)}(\Omega)$ at $V_{GS} = -10 \text{ V}$	0.024
$R_{DS(on)}(\Omega)$ at $V_{GS} = -4.5 \text{ V}$	0.039
I _D (A) per leg	- 8
Configuration	Dual

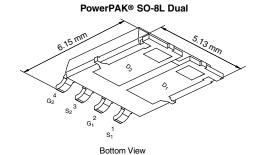
FEATURES

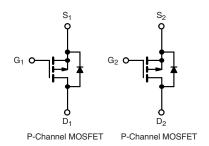
- TrenchFET® Power MOSFET
- 100 % R_a and UIS Tested
- AEC-Q101 Qualified^d
- Material categorization:
 For definitions of compliance please see www.vishav.com/doc?99912





ROHS COMPLIANT HALOGEN FREE





ORDERING INFORMATION	
Package	PowerPAK SO-8L
Lead (Pb)-free and Halogen-free	SQJ941EP-T1-GE3

ABSOLUTE MAXIMUM RATING	S (T _C = 25 °C, unles	s otherwise noted		
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-Source Voltage		V_{DS}	- 30	V
Gate-Source Voltage		V _{GS}	± 20	V
Continuous Drain Currenta	T _C = 25 °C	1	- 8	
Continuous Drain Current	T _C = 125 °C	- I _D	- 8	
Continuous Source Current (Diode Conduction) ^a		I _S	- 8	Α
Pulsed Drain Current ^b		I _{DM}	- 32	
Single Pulse Avalanche Current	L = 0.1 mH	I _{AS}	- 24	
Single Pulse Avalanche Energy		E _{AS}	28.8	mJ
Maximum Power Dissipation ^b	T _C = 25 °C	P _D	55	W
waxiinum Fower Dissipation-	T _C = 125 °C	FD	18.5	VV
Operating Junction and Storage Temperatur	T _J , T _{stg}	- 55 to + 175	°C	
Soldering Recommendations (Peak Tempera	ature) ^{e, f}		260	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-Ambient	PCB Mount ^c	R_{thJA}	85	°C/W
Junction-to-Case (Drain)		R _{thJC}	2.7	C/VV

Notes

- a. Package limited.
- b. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- c. When mounted on 1" square PCB (FR4 material).
- d. Parametric verification ongoing.
- e. See solder profile (www.vishay.com/doc?73257). The PowerPAK SO-8L. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- f. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.



PARAMETER	SYMBOL	TES	T CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static		-			ı	l .	
Drain-Source Breakdown Voltage	V _{DS}	V _{GS} :	= 0, I _D = - 250 μA	- 30	-	-	V
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	V _{GS} , I _D = - 250 μA	- 1.5	- 2.0	- 2.5	V
Gate-Source Leakage	I _{GSS}	V _{DS} =	0 V, V _{GS} = ± 20 V	-	-	± 100	nA
		V _{GS} = 0 V	V _{DS} = - 30 V	-	-	- 1	
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V	V _{DS} = - 30 V, T _J = 125 °C	-	-	- 50	μΑ
		V _{GS} = 0 V	V _{DS} = - 30 V, T _J = 175 °C	-	-	- 150	
On-State Drain Current ^a	I _{D(on)}	V _{GS} = - 10 V	V _{DS} = - 5 V	- 24	-	-	Α
		V _{GS} = - 10 V	I _D = - 9 A	-	0.020	0.024	
Dunin Course On Otata Basistanas		V _{GS} = - 10 V	I _D = - 9 A, T _J = 125 °C	-	0.028	0.034	Ω
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 10 V	I _D = - 9 A, T _J = 175 °C	-	0.032	0.039	
		V _{GS} = - 4.5 V	I _D = - 5 A	-	0.032	0.039	
Forward Transconductance ^b	9 _{fs}	V _{DS} =	- 15 V, I _D = - 2.5 A	-	10	-	S
Dynamic ^b	<u> </u>	<u> </u>					
Input Capacitance	C _{iss}			-	1500	1800	
Output Capacitance	C _{oss}	$V_{GS} = 0 V$	V _{DS} = - 10 V, f = 1 MHz	-	370	445	pF
Reverse Transfer Capacitance	C _{rss}			-	260	315	
Total Gate Charge ^c	Qg			-	35	55	
Gate-Source Charge ^c	Q _{gs}	V _{GS} = - 10 V	$V_{DS} = -15 \text{ V}, I_{D} = -9 \text{ A}$	-	4.6	=-	nC
Gate-Drain Charge ^c	Q _{gd}			-	8.1	=-	
Gate Resistance	R _g		f = 1 MHz	2.8	5.95	9.5	Ω
Turn-On Delay Time ^c	t _{d(on)}			-	49	60	
Rise Time ^c	t _r	V _{DD} = -	- 15 V, R _I = 1.66 Ω	-	35	50	1
Turn-Off Delay Time ^c	t _{d(off)}	$I_D \cong -9 A, Y$	$V_{\rm GEN} = -10 \text{V}, \text{R}_{\rm g} = 6 \Omega$	-	47	60	ns
Fall Time ^c	t _f	7		-	26	33	
Source-Drain Diode Ratings and Char	acteristics ^b	•					
Pulsed Current ^a	I _{SM}			_	_	- 32	Α
	Olvi						

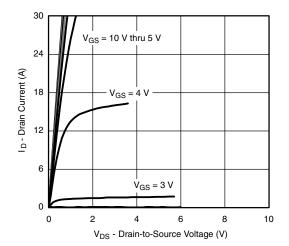
Notes

- a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

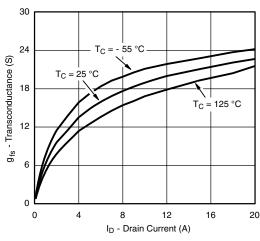
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



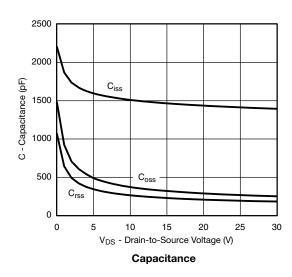
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

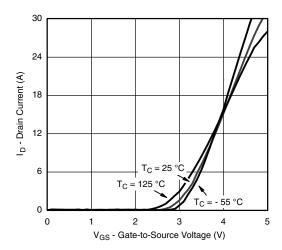


Output Characteristics

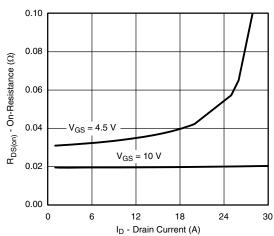


Transconductance

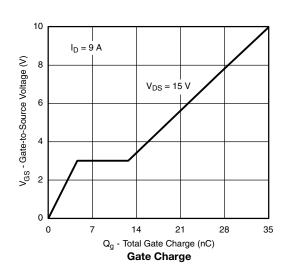




Transfer Characteristics

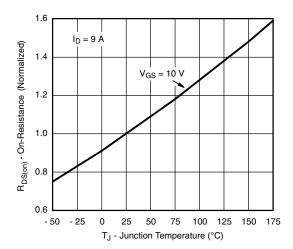


On-Resistance vs. Drain Current

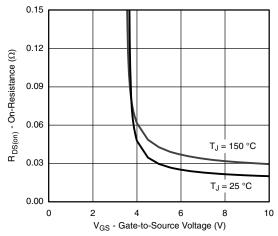




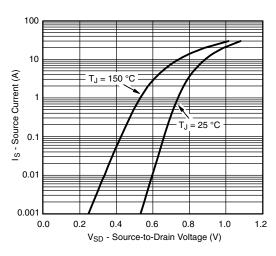
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



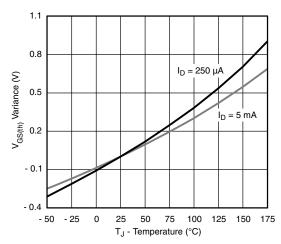
On-Resistance vs. Junction Temperature



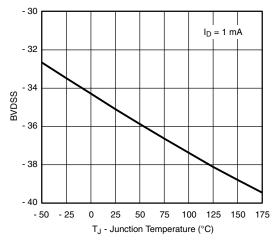
On-Resistance vs. Gate-to-Source Voltage



Source Drain Diode Forward Voltage



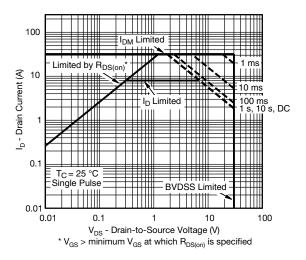
Threshold Voltage



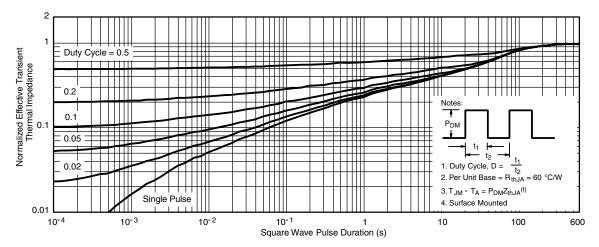
BVDSS vs. Junction Temperature



THERMAL RATINGS ($T_A = 25$ °C, unless otherwise noted)

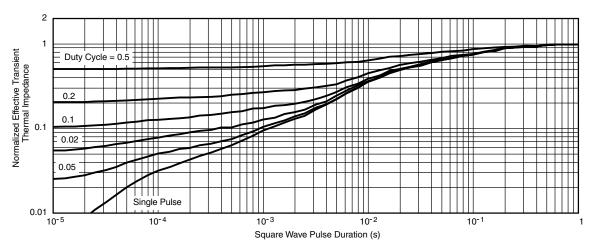


Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient

THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

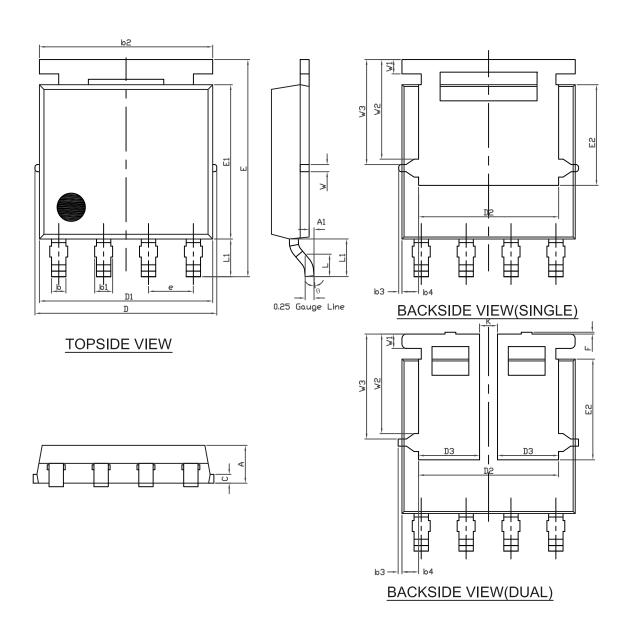
are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?65546.

www.vishay.com

Vishay Siliconix

PowerPAK® SO-8L Case Outline



Package Information

Vishay Siliconix

DIM.		MILLIMETERS		INCHES			
DIM.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
Α	1.00	1.07	1.14	0.039	0.042	0.045	
A1	0.00	-	0.127	0.00	-	0.005	
b	0.33	0.41	0.48	0.013	0.016	0.019	
b1	0.44	0.51	0.58	0.017	0.020	0.023	
b2	4.80	4.90	5.00	0.189	0.193	0.197	
b3		0.094			0.004		
b4		0.47			0.019		
С	0.20	0.25	0.30	0.008	0.010	0.012	
D	5.00	5.13	5.25	0.197	0.202	0.207	
D1	4.80	4.90	5.00	0.189	0.193	0.197	
D2	3.86	3.96	4.06	0.152	0.156	0.160	
D3	1.63	1.73	1.83	0.064	0.068	0.072	
е		1.27 BSC		0.050 BSC			
Е	6.05	6.15	6.25	0.238	0.242	0.246	
E1	4.27	4.37	4.47	0.168	0.172	0.176	
E2 (for Al product)	2.75	2.85	2.95	0.108	0.112	0.116	
E2 (for other product)	3.18	3.28	3.38	0.125	0.129	0.133	
F	-	-	0.15	-	-	0.006	
L	0.62	0.72	0.82	0.024	0.028	0.032	
L1	0.92	1.07	1.22	0.036	0.042	0.048	
K	0.51			0.020			
W	0.23		0.009				
W1	0.41		0.016				
W2	2.82		0.111				
W3	2.96			0.117			
θ	0°	-	10°	0°	-	10°	

ECN: C12-0026-Rev. B, 27-Aug-12

DWG: 5976

Note

• Millimeters will gover



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